ELFA

Datum 981021

PRODUKTINFORMATION

TEKNISK INFORMATION 020-75 80 20 ORDERTEL 020-75 80 00 ORDERFAX 020-75 80 10
TECHNICAL INFORMATION +46 8 580 941 15 ORDERPHONE +46 8 580 941 01 ORDERFAX +46 8 580 941 11
Vi reserverar oss mot fel samt förbehåller oss rätten till ändringar utan föregående meddelande

ELFA artikelnr.

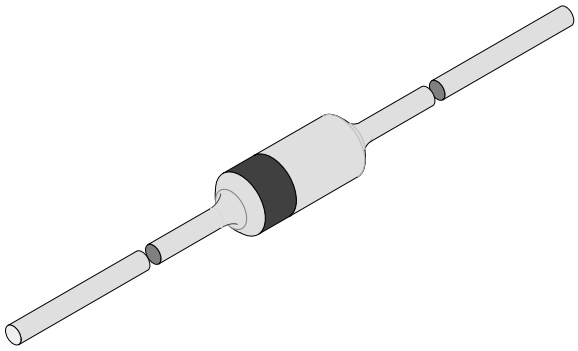
Antal sidor: 07

70-053-09	BZX55/C2V4 zenerdiod
70-053-17	BZX55/C2V7 zenerdiod
70-053-25	BZX55/C3V0 zenerdiod
70-053-33	BZX55/C3V3 zenerdiod
70-053-41	BZX55/C3V6 zenerdiod
70-053-58	BZX55/C3V9 zenerdiod
70-053-66	BZX55/C4V3 zenerdiod
70-053-74	BZX55/C4V7 zenerdiod
70-053-82	BZX55/C5V1 zenerdiod
70-053-90	BZX55/C5V6 zenerdiod
70-054-08	BZX55/C6V2 zenerdiod
70-054-16	BZX55/C6V8 zenerdiod
70-054-24	BZX55/C7V5 zenerdiod
70-054-32	BZX55/C8V2 zenerdiod
70-054-40	BZX55/C9V1 zenerdiod
70-054-57	BZX55/C10 zenerdiod
70-054-65	BZX55/C11 zenerdiod
70-054-73	BZX55/C12 zenerdiod
70-054-81	BZX55/C13 zenerdiod
70-054-99	BZX55/C15 zenerdiod
70-055-07	BZX55/C16 zenerdiod
70-055-15	BZX55/C18 zenerdiod
70-055-23	BZX55/C20 zenerdiod
70-055-31	BZX55/C22 zenerdiod
70-055-49	BZX55/C24 zenerdiod
70-055-56	BZX55/C27 zenerdiod
70-055-64	BZX55/C30 zenerdiod
70-055-72	BZX55/C33 zenerdiod
70-055-80	BZX55/C36 zenerdiod
70-055-98	BZX55/C39 zenerdiod

Silicon Epitaxial Planar Z–Diodes

Features

- Very sharp reverse characteristic
- Low reverse current level
- Very high stability
- Low noise
- Available with tighter tolerances



94 9367

Applications

Voltage stabilization

Absolute Maximum Ratings

T_j = 25°C

Parameter	Test Conditions	Type	Symbol	Value	Unit
Power dissipation	l=4mm, T_L=25˚C		P_V	500	mW
Z–current			I_Z	P_V/V_Z	mA
Junction temperature			T_j	175	˚C
Storage temperature range			T_{stg}	–65...+175	˚C

Maximum Thermal Resistance

T_j = 25°C

Parameter	Test Conditions	Symbol	Value	Unit
Junction ambient	l=4mm, T_L=constant	R_{thJA}	300	K/W

Electrical Characteristics

T_j = 25°C

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Forward voltage	I_F=200mA		V_F			1.5	V

Type	V_{Znom}	I_{ZT} for V_{ZT} [1] and r_{zjT}			r_{zjK} at I_{ZK}		I_R and I_R [2] at V_R			TK_{VZ}
BZX55C...	V	mA	V	Ω	Ω	mA	μA	μA	V	%/K
2V4	2.4	5	2.28 to 2.56	< 85	< 600	1	< 50	< 100	1	–0.09 to –0.06
2V7	2.7	5	2.5 to 2.9	< 85	< 600	1	< 10	< 50	1	–0.09 to –0.06
3V0	3.0	5	2.8 to 3.2	< 85	< 600	1	< 4	< 40	1	–0.08 to –0.05
3V3	3.3	5	3.1 to 3.5	< 85	< 600	1	< 2	< 40	1	–0.08 to –0.05
3V6	3.6	5	3.4 to 3.8	< 85	< 600	1	< 2	< 40	1	–0.08 to –0.05
3V9	3.9	5	3.7 to 4.1	< 85	< 600	1	< 2	< 40	1	–0.08 to –0.05
4V3	4.3	5	4.0 to 4.6	< 75	< 600	1	< 1	< 20	1	–0.06 to –0.03
4V7	4.7	5	4.4 to 5.0	< 60	< 600	1	< 0.5	< 10	1	–0.05 to +0.02
5V1	5.1	5	4.8 to 5.4	< 35	< 550	1	< 0.1	< 2	1	–0.02 to +0.02
5V6	5.6	5	5.2 to 6.0	<25	< 450	1	< 0.1	< 2	1	–0.05 to +0.05
6V2	6.2	5	5.8 to 6.6	< 10	< 200	1	< 0.1	< 2	2	0.03 to 0.06
6V8	6.8	5	6.4 to 7.2	< 8	< 150	1	< 0.1	< 2	3	0.03 to 0.07
7V5	7.5	5	7.0 to 7.9	< 7	< 50	1	< 0.1	< 2	5	0.03 to 0.07
8V2	8.2	5	7.7 to 8.7	< 7	< 50	1	< 0.1	< 2	6.2	0.03 to 0.08
9V1	9.1	5	8.5 to 9.6	< 10	< 50	1	< 0.1	< 2	6.8	0.03 to 0.09
10	10	5	9.4 to 10.6	< 15	< 70	1	< 0.1	< 2	7.5	0.03 to 0.1
11	11	5	10.4 to 11.6	< 20	< 70	1	< 0.1	< 2	8.2	0.03 to 0.11
12	12	5	11.4 to 12.7	< 20	< 90	1	< 0.1	< 2	9.1	0.03 to 0.11
13	13	5	12.4 to 14.1	< 26	< 110	1	< 0.1	< 2	10	0.03 to 0.11
15	15	5	13.8 to 15.6	< 30	< 110	1	< 0.1	< 2	11	0.03 to 0.11
16	16	5	15.3 to 17.1	< 40	< 170	1	< 0.1	< 2	12	0.03 to 0.11
18	18	5	16.8 to 19.1	< 50	< 170	1	< 0.1	< 2	13	0.03 to 0.11
20	20	5	18.8 to 21.2	< 55	< 220	1	< 0.1	< 2	15	0.03 to 0.11
22	22	5	20.8 to 23.3	< 55	< 220	1	< 0.1	< 2	16	0.04 to 0.12
24	24	5	22.8 to 25.6	< 80	< 220	1	< 0.1	< 2	18	0.04 to 0.12
27	27	5	25.1 to 28.9	< 80	< 220	1	< 0.1	< 2	20	0.04 to 0.12
30	30	5	28 to 32	< 80	< 220	1	< 0.1	< 2	22	0.04 to 0.12
33	33	5	31 to 35	< 80	< 220	1	< 0.1	< 2	24	0.04 to 0.12
36	36	5	34 to 38	< 80	< 220	1	< 0.1	< 2	27	0.04 to 0.12
39	39	2.5	37 to 41	< 90	< 500	0.5	< 0.1	< 5	30	0.04 to 0.12
43	43	2.5	40 to 46	< 90	< 600	0.5	< 0.1	< 5	33	0.04 to 0.12
47	47	2.5	44 to 50	< 110	< 700	0.5	< 0.1	< 5	36	0.04 to 0.12
51	51	2.5	48 to 54	< 125	< 700	0.5	< 0.1	< 10	39	0.04 to 0.12
56	56	2.5	52 to 60	< 135	< 1000	0.5	< 0.1	< 10	43	0.04 to 0.12
62	62	2.5	58 to 66	< 150	< 1000	0.5	< 0.1	< 10	47	0.04 to 0.12
68	68	2.5	64 to 72	< 200	< 1000	0.5	< 0.1	< 10	51	0.04 to 0.12
75	75	2.5	70 to 79	< 250	< 1500	0.5	< 0.1	< 10	56	0.04 to 0.12

[1] Tighter tolerances available on request:
BZX55A... ±1% of V_{Znom}
BZX55B... ±2% of V_{Znom}
BZX55F... ±3% of V_{Znom}

[2] at T_j = 150°C

Characteristics (T_j = 25°C unless otherwise specified)

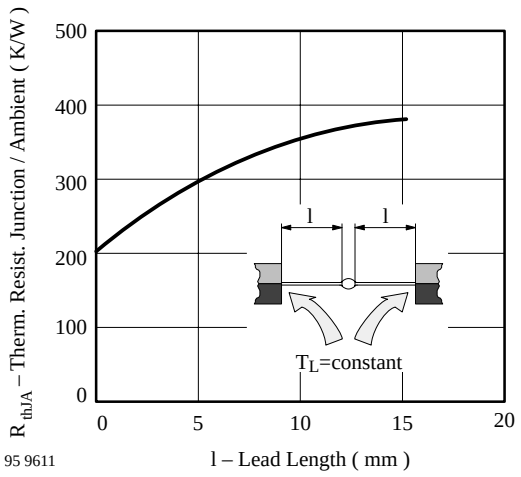


Figure 1. Thermal Resistance vs. Lead Length

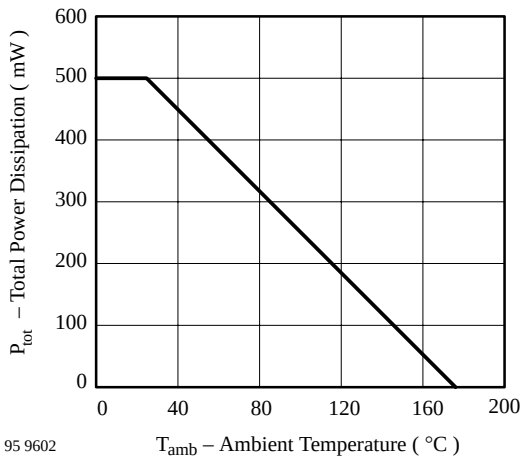


Figure 2. Total Power Dissipation vs. Ambient Temperature

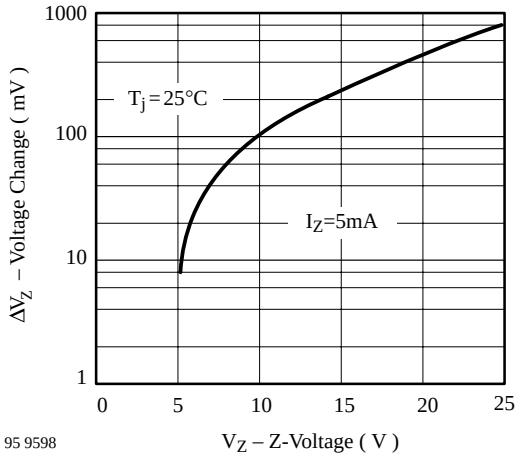


Figure 3. Typical Change of Working Voltage under Operating Conditions at T_{amb}=25°C

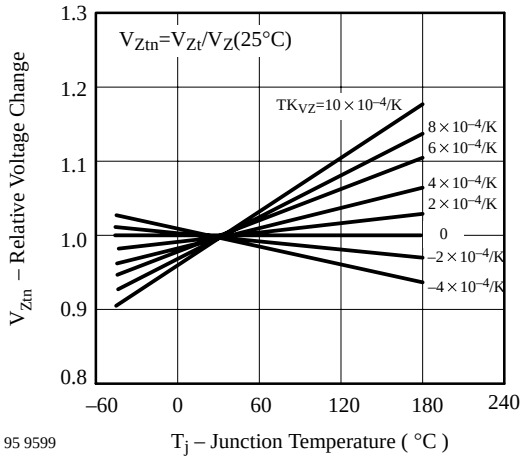


Figure 4. Typical Change of Working Voltage vs. Junction Temperature

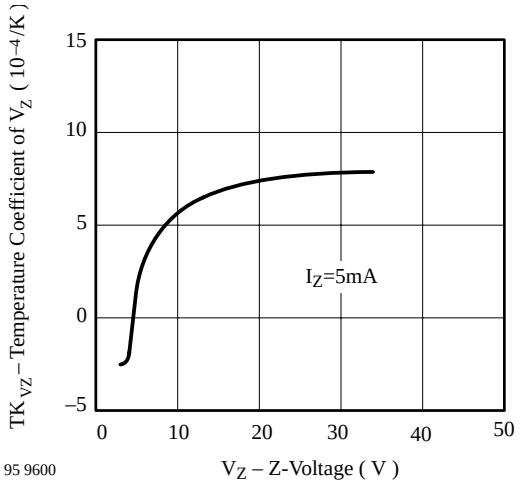


Figure 5. Temperature Coefficient of Vz vs. Z–Voltage

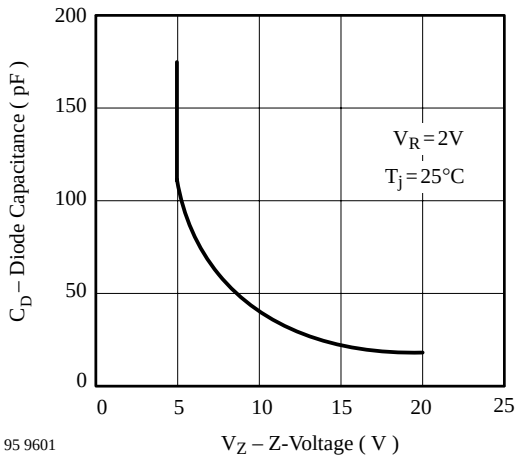


Figure 6. Diode Capacitance vs. Z–Voltage

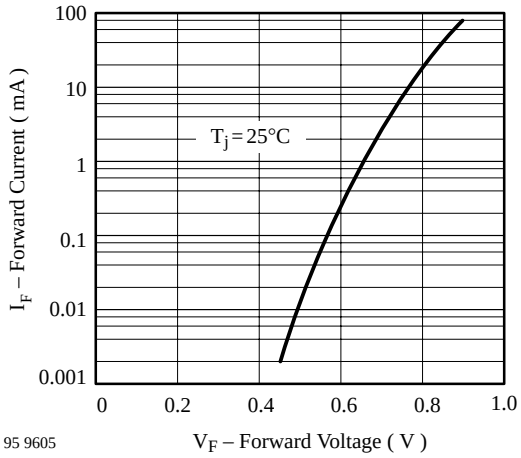


Figure 7. Forward Current vs. Forward Voltage

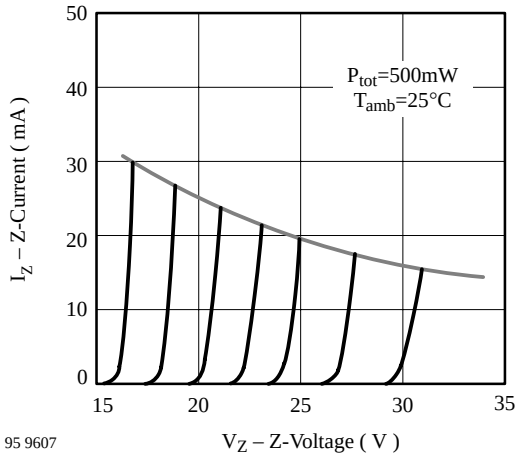


Figure 9. Z–Current vs. Z–Voltage

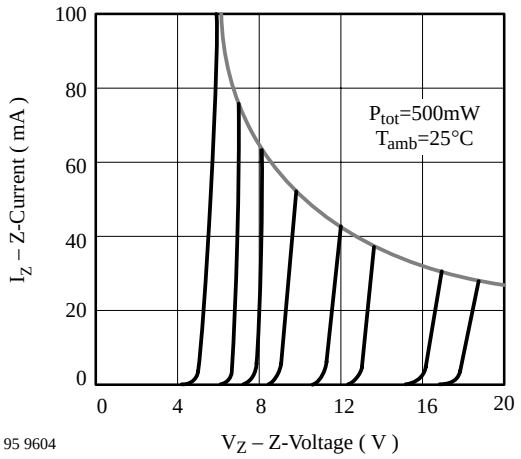


Figure 8. Z–Current vs. Z–Voltage

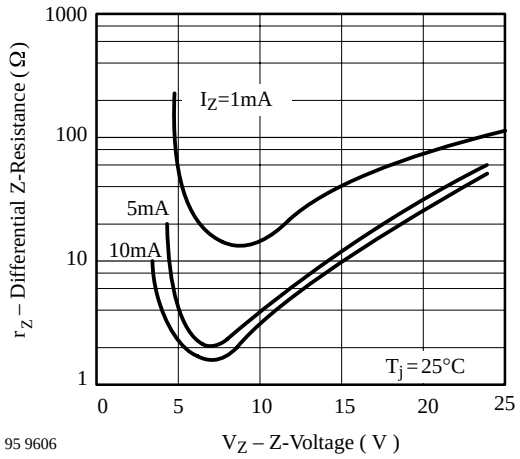


Figure 10. Differential Z–Resistance vs. Z–Voltage

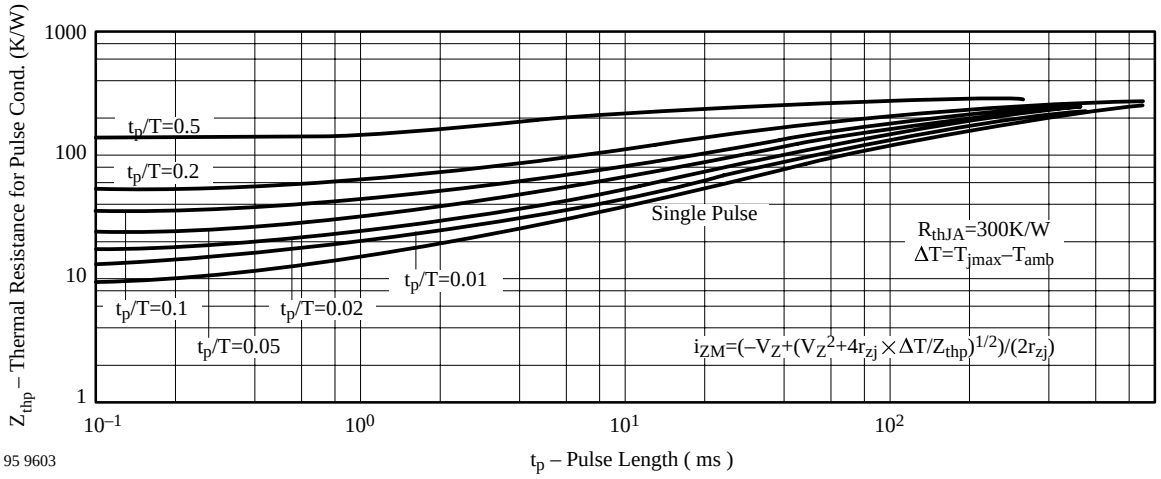


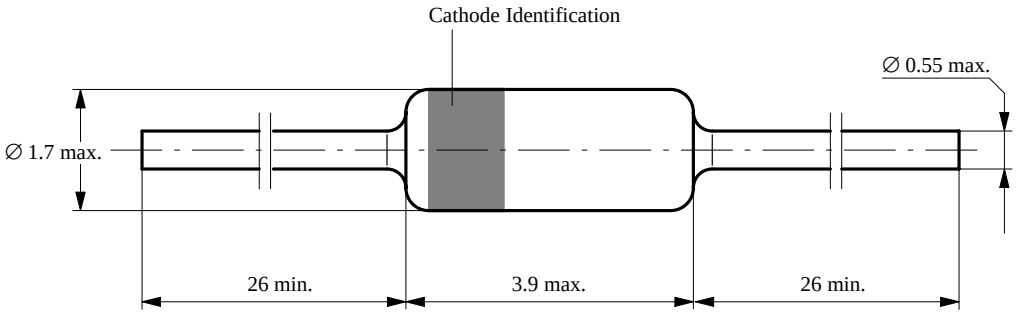
Figure 11. Thermal Response

Dimensions in mm

technical drawings
according to DIN
specifications

94 9366

Standard Glass Case
54 A 2 DIN 41880
JEDEC DO 35
Weight max. 0.3 g



Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.

2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively

2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA

3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.
Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay-Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay-Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany
Telephone: 49 (0)7131 67 2831, Fax number: 49 (0)7131 67 2423